In the Claims:

- 1. (Currently Amended) Gas sensor having first and second sensor regions responding to at least one reactive exhaust gas constituent and having a catalytic agent for converting reactive exhaust gas constituents with a higher catalytic activity in said first sensor region, wherein characterized in that the first sensor region comprises-pores in which traces of at least one catalytically active substance are present as the catalytic agent and further wherein the sensor regions are independent of one another and comprise a resistive semiconductor lager.
- 2. (Currently Amended) Gas sensor according to the preceding claim 1 wherein the second sensor region also comprises pores in which traces of at least one catalytically active substance are present, said and the concentration of catalytically active substance being is-lower than in the first region laver.
- (Currently Amended) Gas sensor according to the preceding claim 1, wherein the
 concentration of catalytically active substance in the second sensor region is zero.
- 4. (Previously Amended) Gas sensor according to claim 1, wherein a platinum metal is employed as the catalytically active material, which is produced by thermolysis of a platinum-containing compound introduced in fluid form into the pores.
- 5. (Cancelled)
- 6. (Currently Amended) Gas sensor according to claim 1, wherein the sensor region is manufactured as a thick-film semiconductor with having a silk-screened pore formation by silk screening.

NY02:466352.1

A34836 PCT USA - 071308.0274

PATENT

- 7. (Currently Amended) Gas sensor according to the preceding claim $\underline{1}$, wherein the sensor region is manufactured of strontium titanate.
- 8. (Currently Amended) Gas sensor arrangement having a gas sensor according to the preceding claim 1, which includes with a parallel evaluation circuit for parallel evaluation of the resistance values of both sensor regions.

NY02:466352.1